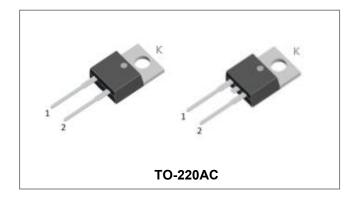


#### Technical Data Data Sheet N0366 Rev. B





## SDUR1560 ULTRAFAST RECTIFIER



### **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

# **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- · High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Maximum Ratings@TA=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	600	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=144°C, In DC	15	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	160	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 15A, Pulse, T <sub>J</sub> = 25°C	1.53	1.7	V
	$V_{F2}$	@ 15A, Pulse, T <sub>J</sub> = 125°C	1.44	1.5	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25°C	0.4	10	μA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125°C	0.3	1	mA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA	31	50	ns

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



Technical Data Data Sheet N0366 Rev. B

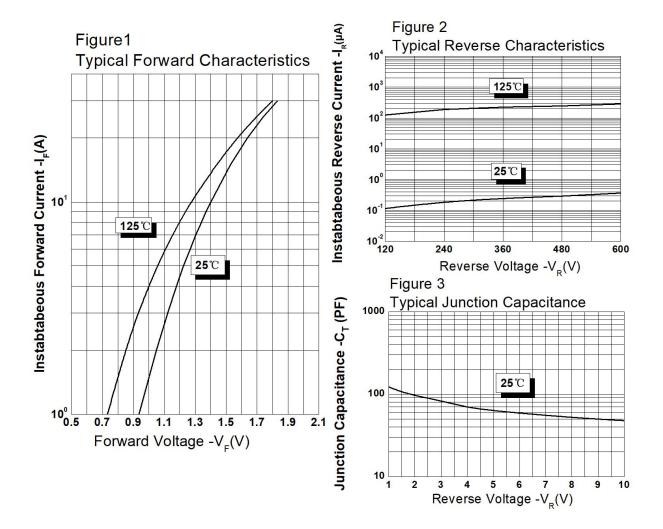




# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> Jc	DC operation	1.2	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

# **Ratings and Characteristics Curves**



<sup>•</sup> China - Germany - Korea - Singapore - United States •

<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •

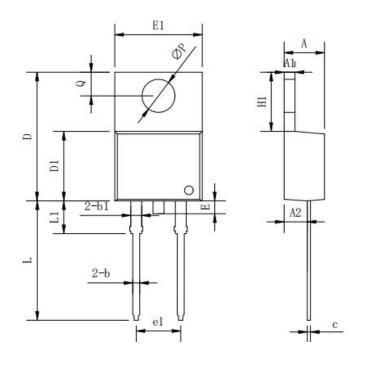


Technical Data Data Sheet N0366 Rev. B



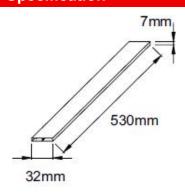


#### **Mechanical Dimensions TO-220AC**

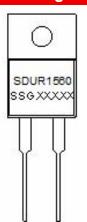


Symbol	Dimensions in millimeters			
-	Min.	Typical	Max.	
Α	3.56	-	4.83	
A1	0.51	-	1.40	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	-	-	1.78	
E1	9.65	10.16	10.67	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.70	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

# **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type 15 = Forward Current (15A) 60 = Reverse Voltage(600V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

# **Ordering Information**

Device	Package	Shipping	
SDUR1560	TO-220AC (Pb-Free)	50 pcs/ tube	

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •

#### **SDUR1560**



#### Technical Data Data Sheet N0366 Rev. B





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